## Adam M Burke

List of Publications by Year in descending order

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| #  | Article  | IF   | CITATIONS |
|----|--|------|-----------|
| 1  | Optical-Beam-Induced Current in InAs/InP Nanowires for Hot-Carrier Photovoltaics. ACS Applied<br>Energy Materials, 2022, 5, 7728-7734.   | 2.5  | 3         |
| 2  | Heat Driven Transport in Serial Double Quantum Dot Devices. Nano Letters, 2021, 21, 988-994.   | 4.5  | 18        |
| 3  | Gate control, g factors, and spin-orbit energy of p -type GaSb nanowire quantum dot devices. Physical<br>Review B, 2021, 103, .  | 1.1  | 1         |
| 4  | Characterization of electrostatically defined bottom-heated InAs nanowire quantum dot systems.<br>New Journal of Physics, 2021, 23, 125007.  | 1.2  | 4         |
| 5  | Hot-carrier separation in heterostructure nanowires observed by electron-beam induced current.<br>Nanotechnology, 2020, 31, 394004.  | 1.3  | 10        |
| 6  | Hot-Carrier Extraction in Nanowire-Nanoantenna Photovoltaic Devices. Nano Letters, 2020, 20,<br>4064-4072.   | 4.5  | 21        |
| 7  | Selective tuning of spin-orbital Kondo contributions in parallel-coupled quantum dots. Physical Review B, 2020, 101, .   | 1.1  | 2         |
| 8  | Side-gated, enhancement mode, InAs nanowire double quantum dot devices—toward controlling<br>transverse electric fields in spin-transport measurements. Nanotechnology, 2019, 30, 144002.      | 1.3  | 6         |
| 9  | Achieving short high-quality gate-all-around structures for horizontal nanowire field-effect transistors. Nanotechnology, 2019, 30, 064001.  | 1.3  | 12        |
| 10 | Thermoelectric Power Factor Limit of a 1D Nanowire. Physical Review Letters, 2018, 120, 177703.  | 2.9  | 30        |
| 11 | Thermoelectric Characterization of the Kondo Resonance in Nanowire Quantum Dots. Physical<br>Review Letters, 2018, 121, 206801.  | 2.9  | 39        |
| 12 | Spectroscopy and level detuning of few-electron spin states in parallel InAs quantum dots. Physical<br>Review B, 2018, 98, .   | 1.1  | 6         |
| 13 | A quantum-dot heat engine operating close to the thermodynamic efficiency limits. Nature<br>Nanotechnology, 2018, 13, 920-924.   | 15.6 | 201       |
| 14 | Bipolar Photothermoelectric Effect Across Energy Filters in Single Nanowires. Nano Letters, 2017, 17,<br>4055-4060.  | 4.5  | 32        |
| 15 | Hybrid Nanowire Ion-to-Electron Transducers for Integrated Bioelectronic Circuitry. Nano Letters, 2017, 17, 827-833.   | 4.5  | 26        |
| 16 | Single-nanowire, low-bandgap hot carrier solar cells with tunable open-circuit voltage.<br>Nanotechnology, 2017, 28, 434001.   | 1.3  | 17        |
| 17 | Nonlinear thermoelectric response due to energy-dependent transport properties of a quantum dot.<br>Physica E: Low-Dimensional Systems and Nanostructures, 2016, 82, 34-38.                    | 1.3  | 17        |
| 18 | Using Polymer Electrolyte Gates to Setâ€andâ€Freeze Threshold Voltage and Local Potential in<br>Nanowireâ€based Devices and Thermoelectrics. Advanced Functional Materials, 2015, 25, 255-262. | 7.8  | 14        |

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|----|---|-----|-----------|
| 19 | InAs Nanowire Transistors with Multiple, Independent Wrap-Gate Segments. Nano Letters, 2015, 15, 2836-2843.   | 4.5 | 36        |
| 20 | Nanoscale polymer electrolytes: Fabrication and applications using nanowire transistors. , 2014, , .  |     | 0         |
| 21 | Determining the stability and activation energy of Si acceptors in AlGaAs using quantum interference<br>in an open hole quantum dot. Physical Review B, 2014, 89, .   | 1.1 | 1         |
| 22 | Electron-Beam Patterning of Polymer Electrolyte Films To Make Multiple Nanoscale Gates for<br>Nanowire Transistors. Nano Letters, 2014, 14, 94-100.   | 4.5 | 27        |
| 23 | Open quantum dots: Physics of the nonâ€Hermitian Hamiltonian. Fortschritte Der Physik, 2013, 61,<br>291-304.  | 1.5 | 8         |
| 24 | The effect of (NH <sub>4</sub> ) <sub>2</sub> S <sub><i>x</i></sub> passivation on the (311)A GaAs surface and its use in AlGaAs/GaAs heterostructure devices. Journal of Physics Condensed Matter, 2013, 25, 325304.         | 0.7 | 8         |
| 25 | Electronic comparison of InAs wurtzite and zincblende phases using nanowire transistors. Physica<br>Status Solidi - Rapid Research Letters, 2013, 7, 911-914.   | 1.2 | 15        |
| 26 | Direct Imaging of Electron States in Open Quantum Dots. Physical Review Letters, 2012, 108, 136804.   | 2.9 | 34        |
| 27 | Origin of gate hysteresis in <mml:math <br="" xmlns:mml="http://www.w3.org/1998/Math/MathML">display="inline"&gt;<mml:mi>p</mml:mi></mml:math> -type Si-doped AlGaAs/GaAs heterostructures.<br>Physical Review B, 2012, 86, . | 1.1 | 12        |
| 28 | Open quantum dots: II. Probing the classical to quantum transition. Journal of Physics Condensed Matter, 2012, 24, 343202.  | 0.7 | 11        |
| 29 | Extreme Sensitivity of the Spin-Splitting and 0.7 Anomaly to Confining Potential in One-Dimensional Nanoelectronic Devices. Nano Letters, 2012, 12, 4495-4502.  | 4.5 | 22        |
| 30 | Impact of Small-Angle Scattering on Ballistic Transport in Quantum Dots. Physical Review Letters, 2012, 108, 196807.  | 2.9 | 29        |
| 31 | Resistively Detected Nuclear Magnetic Resonance in n- and p-Type GaAs Quantum Point Contacts. Nano<br>Letters, 2011, 11, 3147-3150.   | 4.5 | 27        |
| 32 | Open quantum dots—probing the quantum to classical transition. Semiconductor Science and<br>Technology, 2011, 26, 043001.   | 1.0 | 44        |
| 33 | Periodic Scarred States in Open Quantum Dots as Evidence of Quantum Darwinism. Physical Review<br>Letters, 2010, 104, 176801.   | 2.9 | 44        |
| 34 | Imaging scarred states in quantum dots. Journal of Physics Condensed Matter, 2009, 21, 212201.  | 0.7 | 8         |
| 35 | Observation of open quantum dot via low temperature scanning gate microscopy. Journal of Physics:<br>Conference Series, 2009, 150, 022002.  | 0.3 | 0         |
| 36 | Imaging classical and quantum structures in an open quantum dot using scanning gate microscopy.<br>Journal of Vacuum Science & Technology B, 2008, 26, 1488.  | 1.3 | 3         |